

## 1. General description

Silicon Carbide Schottky diode in a TO220-2L plastic package, designed for high frequency switched-mode power supplies.



AEC - Q101 Qualified



## 2. Features and benefits

- New 6th Generation Technology
- Low Forward Voltage Drop
- Low Reverse Leakage Current
- High Forward Surge Capability  $I_{FSM}$
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant
- AEC-Q101 qualified

## 3. Applications

- Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives
- On board charger

## 4. Quick reference data

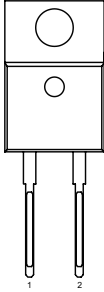

Table 1. Quick reference data

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Symbol	Parameter	Conditions	Notes	Values			Unit
Absolute maximum rating							
V <sub>RRM</sub>	repetitive peak reverse voltage			650			V
I <sub>F(AV)</sub>	average forward current	δ = 0.5 ; square-wave pulse; T <sub>mb</sub> ≤ 138 °C; <a href="#">Fig. 1</a> ; <a href="#">Fig. 2</a> ; <a href="#">Fig. 3</a>		20			A
T <sub>j</sub>	junction temperature			-55 to 175			°C
Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
Static characteristics							
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 20 A; T <sub>j</sub> = 25 °C; <a href="#">Fig. 5</a>		-	1.26	1.40	V
		I <sub>F</sub> = 20 A; T <sub>j</sub> = 150 °C; <a href="#">Fig. 5</a>		-	1.35	1.55	V
Dynamic characteristics							
Q <sub>r</sub>	recovered charge	I <sub>F</sub> = 20 A; dI <sub>F</sub> /dt = 500 A/μs; V <sub>R</sub> = 400 V; T <sub>j</sub> = 25 °C; <a href="#">Fig. 7</a>		-	48	-	nC

## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		
2	A	anode		
mb	mb	mounting base; connected to cathode		

## 6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WNSC6D20650-A	TO220-2L	WNSC6D20650-A6Q	Tube	50	TO220N-2L	04-May-2023

## 7. Marking

Table 4. Marking codes

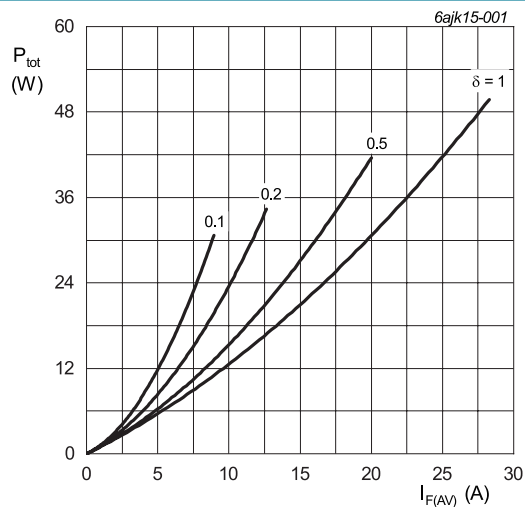
Type number	Marking codes
WNSC6D20650-A	WNSC6D 20650-A

## 8. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

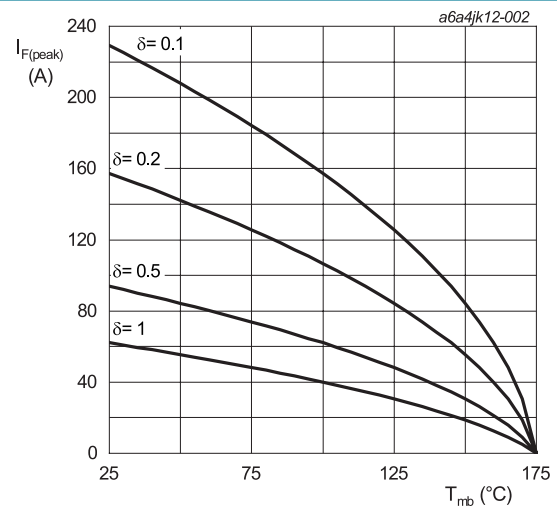
Symbol	Parameter	Conditions	Notes	Values	Unit
$V_{RRM}$	repetitive peak reverse voltage			650	V
$V_{RWM}$	crest working reverse voltage			650	V
$V_R$	reverse voltage	DC		650	V
$I_{F(AV)}$	average forward current	$\delta = 0.5$ ; square-wave pulse; $T_{mb} \leq 138\text{ }^{\circ}\text{C}$ ; Fig. 1; Fig. 2; Fig. 3		20	A
$I_{FRM}$	repetitive peak forward current	$\delta = 0.5$ ; $t_p = 25\text{ }\mu\text{s}$ ; $T_{mb} \leq 138\text{ }^{\circ}\text{C}$ ; square-wave pulse		40	A
$I_{FSM}$	non-repetitive peak forward current	$t_p = 10\text{ ms}$ ; $T_{j(\text{init})} = 25\text{ }^{\circ}\text{C}$ ; sine-wave pulse		140	A
		$t_p = 10\text{ }\mu\text{s}$ ; $T_{j(\text{init})} = 25\text{ }^{\circ}\text{C}$ ; square-wave pulse		1000	A
$I^2t$	$I^2t$ for fusing	sine-wave pulse; $T_{j(\text{init})} = 25\text{ }^{\circ}\text{C}$ ; $t_p = 10\text{ ms}$		98	$\text{A}^2\text{s}$
$T_{stg}$	storage temperature			-55 to 175	$^{\circ}\text{C}$
$T_j$	junction temperature			-55 to 175	$^{\circ}\text{C}$



$$I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$$

$$V_o = 0.984\text{ V}; R_s = 0.0274\text{ }\Omega$$

**Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values**



**Fig. 2. Current derating as a function of mounting base temperature**

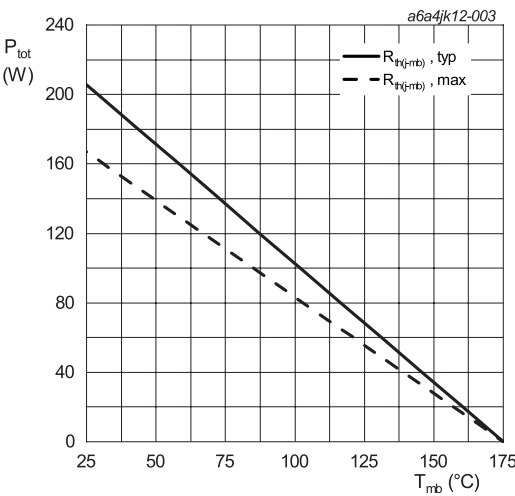


Fig. 3. Total power dissipation as a function of mounting base temperature

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	<a href="#">Fig. 4</a>		-	0.73	0.9	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air		-	60	-	K/W

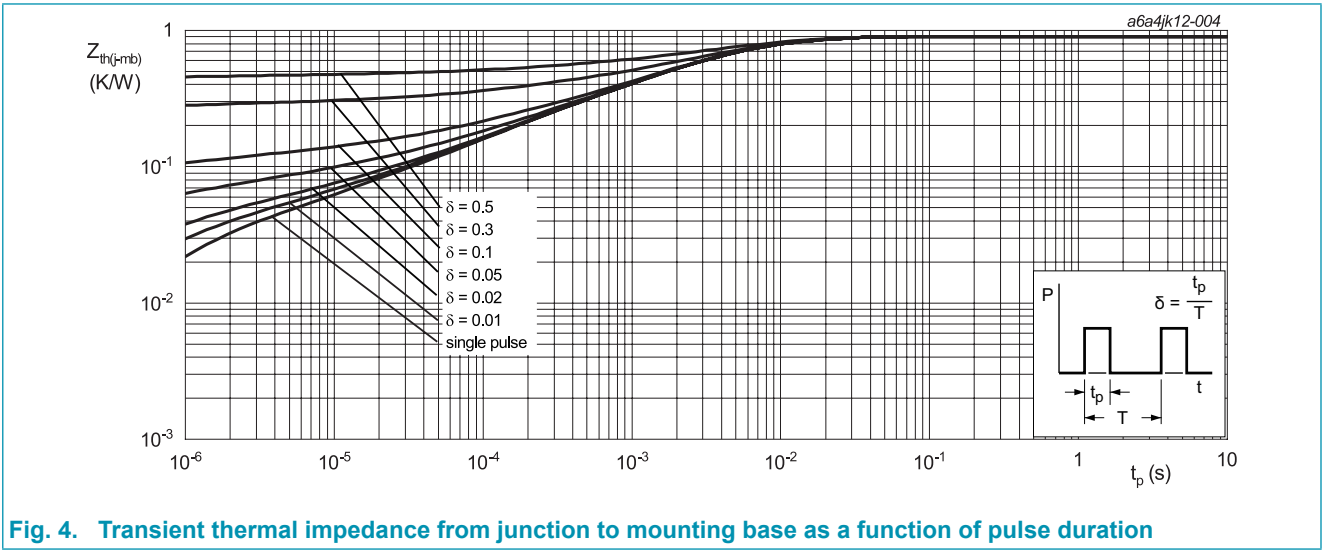
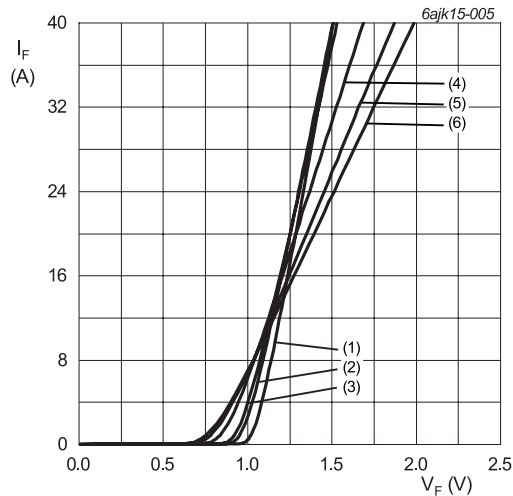


Fig. 4. Transient thermal impedance from junction to mounting base as a function of pulse duration

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Typ	Max	Unit
Static characteristics							
V <sub>F</sub>	forward current	I <sub>F</sub> = 20 A; T <sub>j</sub> = 25 °C; <a href="#">Fig. 5</a>		-	1.26	1.40	V
		I <sub>F</sub> = 20 A; T <sub>j</sub> = 150 °C; <a href="#">Fig. 5</a>		-	1.35	1.55	V
		I <sub>F</sub> = 20 A; T <sub>j</sub> = 175 °C; <a href="#">Fig. 5</a>		-	1.40	1.60	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 650 V; T <sub>j</sub> = 25 °C; <a href="#">Fig. 6</a>		-	2	100	μA
		V <sub>R</sub> = 650 V; T <sub>j</sub> = 175 °C; <a href="#">Fig. 6</a>		-	30	400	μA
Dynamic characteristics							
Q <sub>r</sub>	recovered charge	I <sub>F</sub> = 20 A; V <sub>R</sub> = 400 V; dI <sub>F</sub> /dt = 500 A/μs; T <sub>j</sub> = 25 °C; <a href="#">Fig. 7</a>		-	48	-	nC
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 1 V; T <sub>j</sub> = 25 °C		-	1005	-	pF
		f = 1 MHz; V <sub>R</sub> = 300 V; T <sub>j</sub> = 25 °C		-	110	-	pF
		f = 1 MHz; V <sub>R</sub> = 600 V; T <sub>j</sub> = 25 °C		-	102	-	pF
E <sub>as</sub>	non-repetitive avalanche energy	I <sub>R</sub> = 7.8 A; L = 5 mH; T <sub>j(init)</sub> = 25 °C		150	-	-	mJ



$V_o = 0.984\text{ V}$ ;  $R_s = 0.0274\text{ }\Omega$   
(1)  $T_J = -55\text{ }^\circ\text{C}$ ; typical values  
(2)  $T_J = 0\text{ }^\circ\text{C}$ ; typical values  
(3)  $T_J = 25\text{ }^\circ\text{C}$ ; typical values  
(4)  $T_J = 100\text{ }^\circ\text{C}$ ; typical values  
(5)  $T_J = 150\text{ }^\circ\text{C}$ ; typical values  
(6)  $T_J = 175\text{ }^\circ\text{C}$ ; typical values

Fig. 5. Forward current as a function of forward voltage; typical values

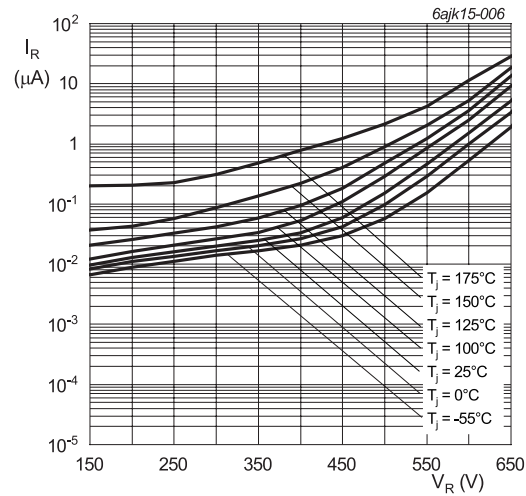


Fig. 6. Reverse leakage current as a function of reverse voltage; typical value

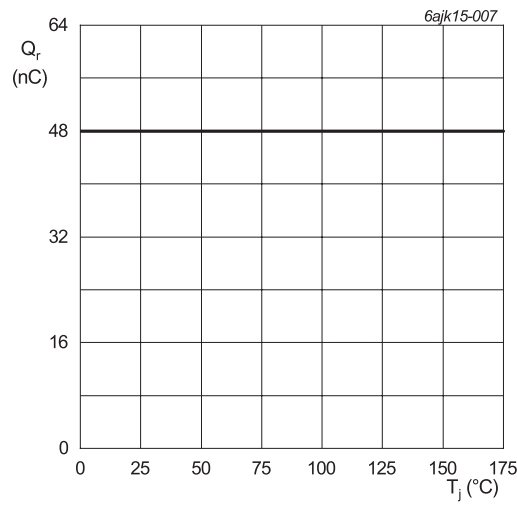
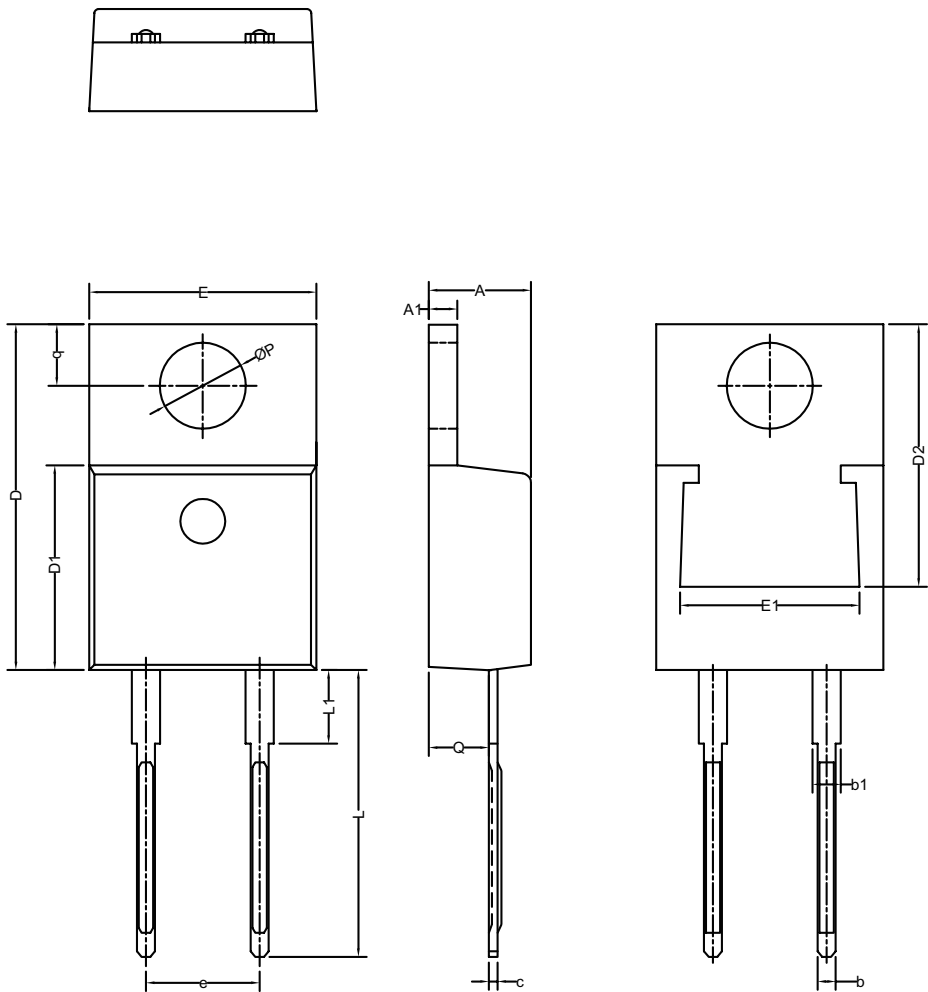


Fig. 7. Recovered charge as a function of junction temperature

11. Package outline

Plastic single-ended package;heatsink mounted;1 mounting hole; 2 leads TO-220AB TO220-2L



Note:  
All dimensions do not include mold flash or protrusion.

Unit	A	A1	b	b1	c	D	D1	D2	E	E1	e	L	L1	P	Q	q
min	4.40	1.20	0.76	1.20	0.35	15.15	9.00	12.20	9.96	7.60	5.08 (BSC)	12.70	2.80	3.75	2.50	2.60
max	4.72	1.40	0.92	1.36	0.46	15.80	9.32	13.00	10.40	8.20		13.20	3.30	3.88	2.79	2.90



## 12. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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- [2] The term 'short data sheet' is explained in section "Definitions".
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